



## 6-Pin DIP Optoisolators Transistor Output

The H11AV1,A and H11AV2,A devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector.

- Guaranteed 70 Volt V(BR)CEO Minimum
- 'A' Suffix = 0.400" Wide Spaced Leadform (Same as 'T' Suffix. Refer to Leadform Options Section in Opto Data Book.)
- *To order devices that are tested and marked per VDE 0884 requirements, the suffix "V" must be included at end of part number. VDE 0884 is a test option.*

### Applications

- General Purpose Switching Circuits
- Interfacing and coupling systems of different potentials and impedances
- Monitor and Detection Circuits
- Regulation and Feedback Circuits
- Solid State Relays

### MAXIMUM RATINGS (TA = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
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#### INPUT LED

Reverse Voltage	VR	6	Volts
Forward Current — Continuous	IF	60	mA
LED Power Dissipation @ TA = 25°C with Negligible Power in Output Detector Derate above 25°C	PD	120 1.41	mW mW/°C

#### OUTPUT TRANSISTOR

Collector-Emitter Voltage	VCEO	70	Volts
Emitter-Base Voltage	VEBO	7	Volts
Collector-Base Voltage	V <sub>CBO</sub>	70	Volts
Collector Current — Continuous	I <sub>C</sub>	150	mA
Detector Power Dissipation @ TA = 25°C with Negligible Power in Input LED Derate above 25°C	PD	150 1.76	mW mW/°C

#### TOTAL DEVICE

Isolation Surge Voltage <sup>(1)</sup> (Peak ac Voltage, 60 Hz, 1 sec Duration)	V <sub>ISO</sub>	7500	Vac(pk)
Total Device Power Dissipation @ TA = 25°C Derate above 25°C	PD	250 2.94	mW mW/°C
Ambient Operating Temperature Range <sup>(2)</sup>	T <sub>A</sub>	-55 to +100	°C
Storage Temperature Range <sup>(2)</sup>	T <sub>Stg</sub>	-55 to +150	°C
Soldering Temperature (10 sec, 1/16" from case)	T <sub>L</sub>	260	°C

1. Isolation surge voltage is an internal device dielectric breakdown rating.  
For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.
2. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.

Preferred devices are Motorola recommended choices for future use and best overall value.  
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**H11AV1,A\***

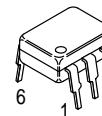
[CTR = 100% Min]

**H11AV2,A**

[CTR = 50% Min]

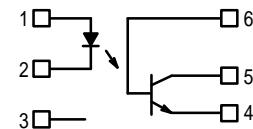
\*Motorola Preferred Devices

#### STYLE 1 PLASTIC



STANDARD THRU HOLE  
CASE 730A-04

#### SCHEMATIC



PIN 1. LED ANODE  
2. LED CATHODE  
3. N.C.  
4. Emitter  
5. Collector  
6. Base

# H11AV1,A H11AV2,A

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  unless otherwise noted)<sup>(1)</sup>

Characteristic	Symbol	Min	Typ <sup>(1)</sup>	Max	Unit
<b>INPUT LED</b>					
Forward Voltage ( $I_F = 10 \text{ mA}$ ) $T_A = 25^\circ\text{C}$ $T_A = -55^\circ\text{C}$ $T_A = 100^\circ\text{C}$	$V_F$	0.8 0.9 0.7	1.15 1.3 1.05	1.5 1.7 1.4	Volts
Reverse Leakage Current ( $V_R = 6 \text{ V}$ )	$I_R$	—	—	10	$\mu\text{A}$
Capacitance ( $V = 0 \text{ V}$ , $f = 1 \text{ MHz}$ )	$C_J$	—	18	—	pF
<b>OUTPUT TRANSISTOR</b>					
Collector-Emitter Dark Current ( $V_{CE} = 10 \text{ V}$ )	$I_{CEO}$	—	5	50	nA
Collector-Base Dark Current ( $V_{CB} = 10 \text{ V}$ )	$I_{CBO}$	—	0.5	—	nA
Collector-Emitter Breakdown Voltage ( $I_C = 1 \text{ mA}$ )	$V_{(BR)CEO}$	70	100	—	Volts
Collector-Base Breakdown Voltage ( $I_C = 100 \mu\text{A}$ )	$V_{(BR)CBO}$	70	100	—	Volts
Emitter-Collector Breakdown Voltage ( $I_E = 100 \mu\text{A}$ )	$V_{(BR)ECO}$	7	8	—	Volts
DC Current Gain ( $I_C = 2 \text{ mA}$ , $V_{CE} = 10 \text{ V}$ ) (Typical Value)	$h_{FE}$	—	500	—	—
Collector-Emitter Capacitance ( $f = 1 \text{ MHz}$ , $V_{CE} = 10 \text{ V}$ )	$C_{CE}$	—	4.5	—	pF
<b>COUPLED</b>					
Output Collector Current ( $I_F = 10 \text{ mA}$ , $V_{CE} = 10 \text{ V}$ ) H11AV1, H11AV1A H11AV2, H11AV2A	$I_C$ (CTR) <sup>(2)</sup>	10 (100) 5 (50)	15 (150) 10 (100)	30 (300) —	mA (%)
Collector-Emitter Saturation Voltage ( $I_C = 2 \text{ mA}$ , $I_F = 20 \text{ mA}$ )	$V_{CE(sat)}$	—	0.15	0.4	Volts
Turn-On Time ( $I_C = 2 \text{ mA}$ , $V_{CC} = 10 \text{ V}$ , $R_L = 100 \Omega$ ) <sup>(3)</sup>	$t_{on}$	—	5	15	$\mu\text{s}$
Turn-Off Time ( $I_C = 2 \text{ mA}$ , $V_{CC} = 10 \text{ V}$ , $R_L = 100 \Omega$ ) <sup>(3)</sup>	$t_{off}$	—	4	15	$\mu\text{s}$
Isolation Voltage ( $f = 60 \text{ Hz}$ , $t = 1 \text{ sec}$ ) <sup>(4)</sup>	$V_{ISO}$	7500	—	—	Vac(pk)
Isolation Resistance ( $V = 500 \text{ V}$ ) <sup>(4)</sup>	$R_{ISO}$	$10^{11}$	—	—	$\Omega$
Isolation Capacitance ( $V = 0 \text{ V}$ , $f = 1 \text{ MHz}$ ) <sup>(4)</sup>	$C_{ISO}$	—	0.2	0.5	pF

1. Always design to the specified minimum/maximum electrical limits (where applicable).

2. Current Transfer Ratio (CTR) =  $I_C/I_F \times 100\%$ .

3. For test circuit setup and waveforms, refer to Figure 11.

4. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

## TYPICAL CHARACTERISTICS

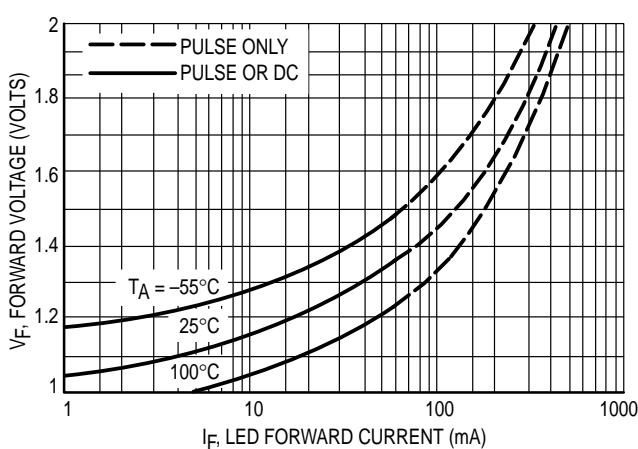


Figure 1. LED Forward Voltage versus Forward Current

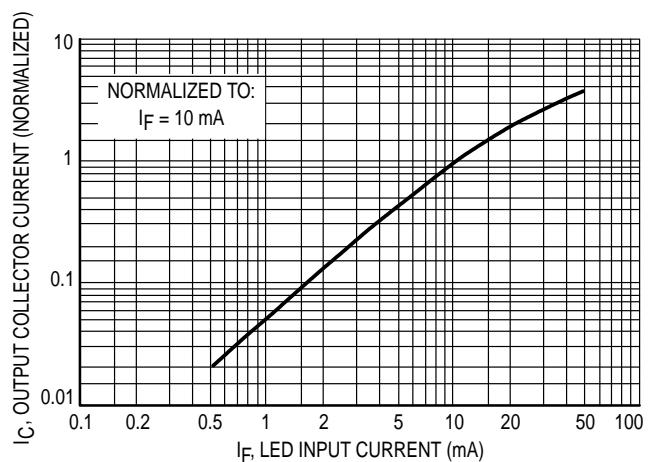


Figure 2. Output Current versus Input Current